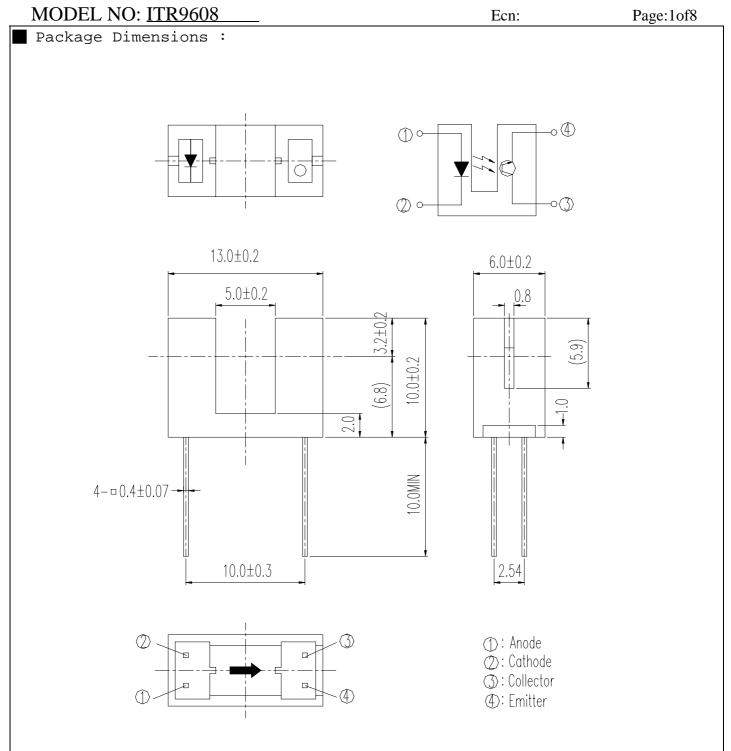


Device Number: <u>DRX-096-028</u> REV: <u>1.1</u>



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⊘Notes:

- 1.All dimensions are in millimeter.
- 2.General Tolerance: ± 0.2mm
- 3. Lead spacing is measured where the lead emerge from the package.
- 4. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 5. These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
- 6.When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

Descriptions:

The ITR9608 (Slot Optical Switch) is a gallium arsenide infrared emitting diode which is coupled with a silicon photo transistor in a plastic housing. The packaging system is designed to optimizes the mechanical resolution, coupling efficiency, and insulates ambient light. The slot in the housing a provides a means of interrupting the signal with printer, scanner, copier, or other opaque material, switching the output from an "ON" to OFF" state.

Features:

- · Wide gap between light emitter and detector(5.0mm)
- · High sensing accuracy
- · PWB mounting type package

Applications:

- · Copier
- · Printer
- · Facsimile
- · Ticket vending machine
- · Opto-electronic switch



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Absolute Maximum Ratings (Ta=25 $^{\circ}$ C)

	Parameter		Ratings	Unit
	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
Input	Reverse Voltage	$V_{\scriptscriptstyle R}$	5	V
	Forward Current	$\mathtt{I}_{\mathtt{F}}$	50	mA
	Peak Forward Current Pulse width $\leq 100 \mu \mathrm{s}$, Duty cycle=1%	$\mathtt{I}_{\mathtt{FP}}$	1	A
	Collector Power Dissipation	P_{c}	75	mW
Output	Collector Current	I_{c}	20	mA
	Collector-Emitter Voltage	V_{ceo}	30	V
	Emitter-Collector Voltage	$V_{\scriptscriptstyle ECO}$	5	V
Operat	Operating Temperature		-25~+85	$^{\circ}\!\mathbb{C}$
Storage Temperature		Tstg	-40~+85	$^{\circ}\!\mathbb{C}$
	Lead Soldering Temperature (1/16 inch from body for 5 seconds)		260	$^{\circ}$ C

Electro-Optical Characteristics (Ta= 25° C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Condition
Input	Forward Voltage	$V_{\scriptscriptstyle F}$	_	1.2	1.5	V	$I_F = 20 \text{mA}$
	Reverse Current	$I_{\scriptscriptstyle R}$	_	_	10	μ A	$V_R = 5V$
	Peak Wavelength	λ,	-	940	_	nm	$I_F = 20 \text{mA}$
Output	Collector Dark Current	$I_{\scriptscriptstyle ext{CEO}}$	-	_	100	nA	$V_{CE} = 20V$ Ee=0mW/cm ²
Transfer Characteristic	C-E Saturation Voltage	V _{CE} (sat)	_	_	0.4	V	$I_c=0.5mA$ $Ee=10mW/cm^2$
	Collector Current	I _C (ON)	0.5	-	-	mA	$V_{CE} = 5V$ $I_F = 20mA$
	Rise time	t _r	-	15	_	$\mu \sec$	$V_{CE} = 5V$
	Fall time	t _f	_	15	_	$\mu \sec$	$ extsf{I}_{ extsf{c}} extsf{=}1 extsf{mA} extsf{R}_{ extsf{L}} extsf{=}1 extsf{K}\Omega$



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MODEL NO: <u>ITR9608</u> ■ Typical Characteristics For IR

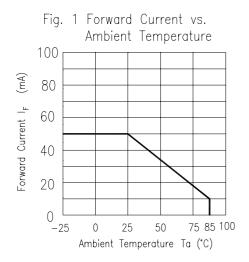


Fig. 3 Peak Emission Wavelength vs.
Ambient Temperature

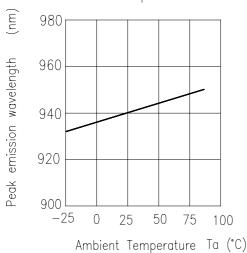


Fig. 5 Forward Voltage vs.

Ambient Temperature

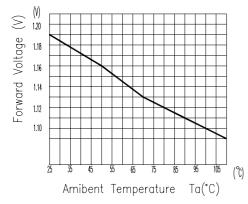


Fig. 2 Spectral Distribution

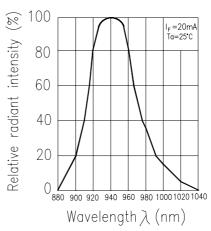


Fig. 4 Forward Current vs. Forward Voltage

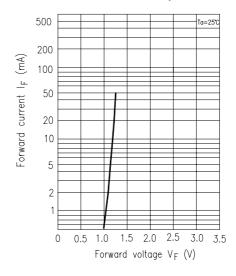
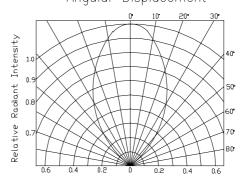


Fig. 6 Relative Radiant Intensity vs Angular Displacement





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MODEL NO: <u>ITR9608</u> Typical Characteristics For PT

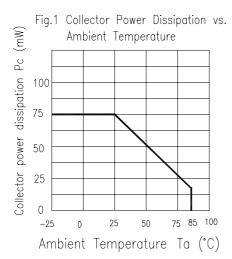
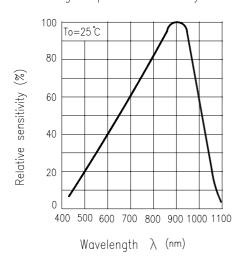
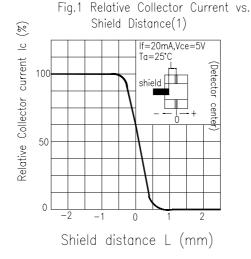


Fig.3 Spectral Sensitivity



Typical Characteristics For ITR



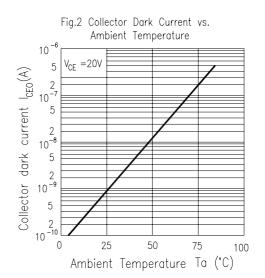
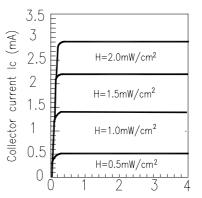
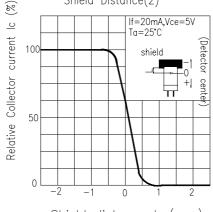


Fig.4 Collector Current vs.
Collector—emitter Voltage



Collector-emitter Voltage V CF (V)

Fig.2 Relative Collector Current vs. Shield Distance(2)



Shield distance L (mm)



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Reliability test item and condition

The reliability of products shall be satisfied with item listed below:

Confidence level :90% LTPD:10%

Parameter	Purpose & Condition	Failure	Samples(n)
		Judgement Criteria	Defective(c)
Temperature Cycle	Evaluates product's ability		n =22 , c=0
	to withstand exposure to	$I_R \ge U \times 2$	
	high temperature, low	$ \begin{array}{c} \operatorname{Ic(on)} \leq L \times 0.8 \\ V_{F} \geq U \times 1.2 \end{array} $	
	temperature, and temperature	F = 0 11 112	
	variation between two limit		
	temperature. Standard test	U: Upper	
	Condition:	specification	
	85°C ~25°C ~-55°C ~25°C	limit	
		L: Lower	
	30min 5min 30min 5min	specification	
	50 cycle	limit	
Thermal Shock	Evaluates product's ability to		n =22 , c=0
	withstand rapid temperature		
	change Standard test		
	Condition:		
	85°C ~ -55°C		
	5min 5min		
	50cycle		
High Temperature	Evaluates product's ability to		n =22 , c=0
Storage	withstand prolonged storage		
	at high temperature Standard		
	test Condition:		
	Temperature : 100 °C		
	Time: 1000hrs		
Low Temperature	Evaluates product's ability to		n =22 , c=0
Storage	withstand prolonged storage		
	at low temperature Standard		
	test Condition:		
	Temperature : -55 °C		
	Time: 1000hrs		

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Parameter	Purpose & Condition	Failure	Samples(n)
		Judgement Criteria	Defective(c)
Operating Life Test	Evaluates product's endurance		n =22 , c=0
	to prolonged electrical or	$I_R \ge U \times 2$	
	temperature stresses. Standard		
	test Condition:	· F = 0 ii 1.2	
	$V_{CE}=5V$		
	$I_F=20mA$	U: Upper	
	Time: 1000hrs	specification	
High Temperature	Evaluates product's ability to	limit	n =22 , c=0
	withstand prolonged storage	L: Lower	
High Humidity	at high temperature and high	specification	
	humidity. Standard test	limit	
	Condition:		
	Temperature: 85°℃		
	Relative humidity:85%		
	Time: 1000hrs		
Soldering Heat	Evaluates product's ability to		n =22 , c=0
	withstand soldering heat		
	Standard test conditions		
	Solder temperature : 260±5°C		
	Solder time: 10 seconds		

Supplements

1.Parts

(1) Chip

Type	Material	Peak Wavelength
IR	GaAs	940 nm
PT	Silicon	860 nm

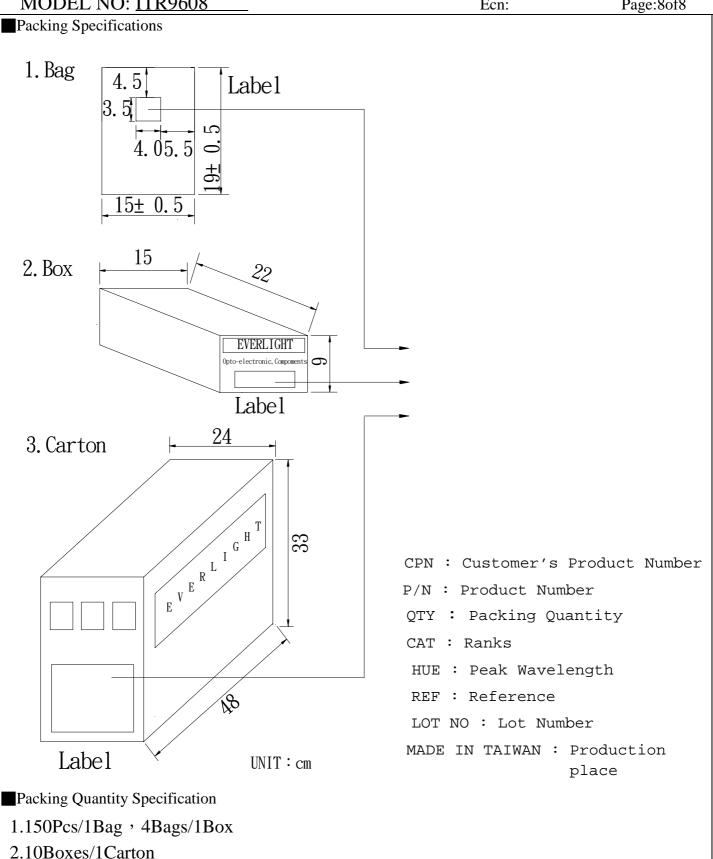
(2)Material

Type	Lead frame	Wire	Part Package	Holder
Material	SPCC	Gold	Epoxy	NYLON



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单击下面可查看定价,库存,交付和生命周期等信息

>>Everlight(亿光)